# Trench-based Schottky Diode, 500 mA, 20 V

# NSR05201MX4

These Trench Schottky diodes are optimized for low forward voltage drop and low leakage current that offers the most optimal power dissipation in applications. They are housed in space saving micro-packaging ideal for space constrained applications.

#### **Features**

- Smallest Package Available (01005); 0.445 x 0.24mm
- 500 mA of Continuous Forward Current
- Low Forward Voltage Drop 350 mV (Typical) @  $I_F = 100 \text{ mA}$
- Low Reverse Current 40  $\mu$ A (Typical) @  $V_R = 20 \text{ V}$
- Very Low Reverse Recovery Time 8 ns Maximum
- Low Capacitance 20 pF Typical

### **Typical Applications**

- Mobile and Wearable Devices
- Battery Chargers
- Buck and Boost dc-dc Converters
- Reverse Voltage and Current Protection
- Clamping & Protection

### **MAXIMUM RATINGS**

|   | Rating                            | Symbol           | Value        | Unit    |
|---|-----------------------------------|------------------|--------------|---------|
| Forward Current   | (DC)                              | I <sub>F</sub>   | 500          | mA      |
| Reverse Voltage   |                                   | $V_{R}$          | 20           | V       |
| Repetitive Peak Forward Current<br>(Pulse Wave = 1 sec, Duty Cycle = 66%) |                                   | I <sub>FRM</sub> | 1.0          | Α       |
| ESD Rating:   | Human Body Model<br>Machine Model | ESD              | >8.0<br>>400 | kV<br>V |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



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#### **MARKING** DIAGRAM



X4DFN2 (01005) CASE 718AA



T = Specific Device Code

M = Date Code

#### **ORDERING INFORMATION**

| Device         | Package             | Shipping†              |
|----------------|---------------------|------------------------|
| NSR05201MX4T5G | X4DFN2<br>(Pb-Free) | 10000 /<br>Tape & Reel |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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#### NSR05201MX4

#### THERMAL CHARACTERISTICS

| Characteristic  | Symbol                             | Max          | Unit       |
|---|------------------------------------|--------------|------------|
| Thermal Resistance Junction-to-Ambient (Note 1) Total Power Dissipation @ T <sub>A</sub> = 25°C | R <sub>θJA</sub><br>P <sub>D</sub> | 614.9<br>203 | °C/W<br>mW |
| Thermal Resistance Junction-to-Ambient (Note 2) Total Power Dissipation @ T <sub>A</sub> = 25°C | R <sub>θJA</sub><br>P <sub>D</sub> | 239.4<br>522 | °C/W<br>mW |
| Junction Temperature Range  | TJ                                 | -55 to +125  | °C         |
| Storage Temperature Range   | T <sub>STG</sub>                   | -55 to +150  | °C         |
| Lead Solder Temperature - Maximum (10 seconds)  | TL                                 | 260          | °C         |

- 1. Mounted onto a 4 in<sup>2</sup> FR-4 board 10 mm<sup>2</sup> 1 oz. Cu 0.06' thick single-sided. Operating to steady state.
- 2. Mounted onto a 4 in<sup>2</sup> FR-4 board 2 cm<sup>2</sup> 1 oz. Cu 0.06' thick single-sided. Operating to steady state.

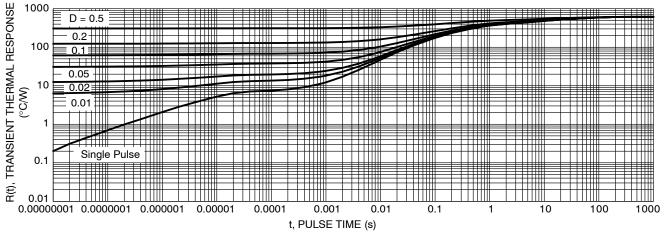


Figure 1. Thermal Response (Note 1)

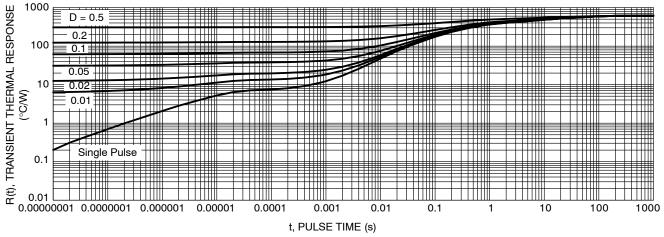


Figure 2. Thermal Response (Note 2)

# NSR05201MX4

**ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted)

| Characteristic   | Symbol          | Min | Тур               | Max               | Unit |
|--|-----------------|-----|-------------------|-------------------|------|
| Reverse Leakage<br>(V <sub>R</sub> = 7 V)<br>(V <sub>R</sub> = 20 V)                                   | I <sub>R</sub>  |     | 5.0<br>40         | 60<br>110         | μΑ   |
| Forward Voltage<br>(I <sub>F</sub> = 100 mA)<br>(I <sub>F</sub> = 200 mA)<br>(I <sub>F</sub> = 500 mA) | V <sub>F</sub>  |     | 350<br>400<br>450 | 480<br>530<br>600 | mV   |
| Total Capacitance<br>(V <sub>R</sub> = 5.0 V, f = 1 MHz)   | C <sub>T</sub>  |     | 20                |                   | pF   |
| Reverse Recovery Time<br>(I <sub>F</sub> = I <sub>R</sub> = 10 mA, I <sub>R(REC)</sub> = 1.0 mA)       | t <sub>rr</sub> |     |                   | 8.0               | ns   |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

# **TYPICAL CHARACTERISTICS**

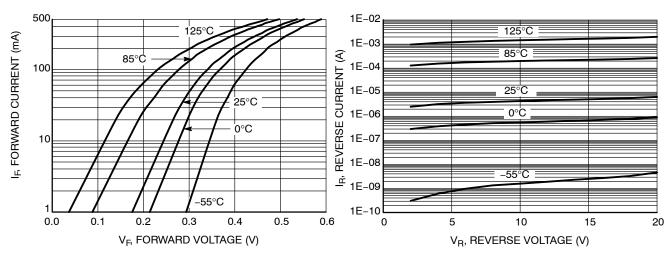


Figure 3. Forward Voltage

Figure 4. Leakage Current

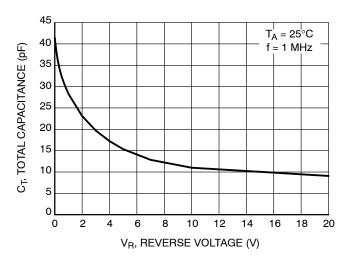
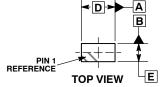


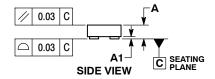
Figure 5. Total Capacitance

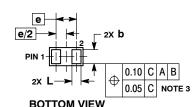
#### X4DFN2, 0.445x0.24, 0.27P CASE 718AA **ISSUE A**



**DATE 21 MAR 2017** 







#### NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.

  CONTROLLING DIMENSION: MILLIMETERS.

  EXPOSED COPPER ALLOWED AS SHOWN.

|     | MILLIMETERS |       |       |  |
|-----|-------------|-------|-------|--|
| DIM | MIN         | NOM   | MAX   |  |
| Α   | 0.15        | 0.18  | 0.21  |  |
| A1  |             |       | 0.03  |  |
| b   | 0.170       | 0.185 | 0.200 |  |
| D   | 0.415       | 0.445 | 0.475 |  |
| Е   | 0.210       | 0.240 | 0.270 |  |
| е   | 0.270 BSC   |       |       |  |
| L   | 0.105       | 0.120 | 0.135 |  |

#### **GENERIC MARKING DIAGRAMS\***

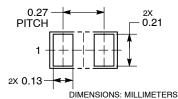




X = Specific Device Code

\*This information is generic. Please refer to device data sheet for actual part marking. Some products may not follow the Generic Marking.

#### RECOMMENDED **MOUNTING FOOTPRINT\***



See Application Note AND8398/D for more mounting details

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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|------------------|---------------------------|---|-------------|--|
| DESCRIPTION:     | X4DFN2, 0.445X0.24, 0.27F |   | PAGE 1 OF 1 |  |

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